

第一章

1.1 Semiconductor Materials

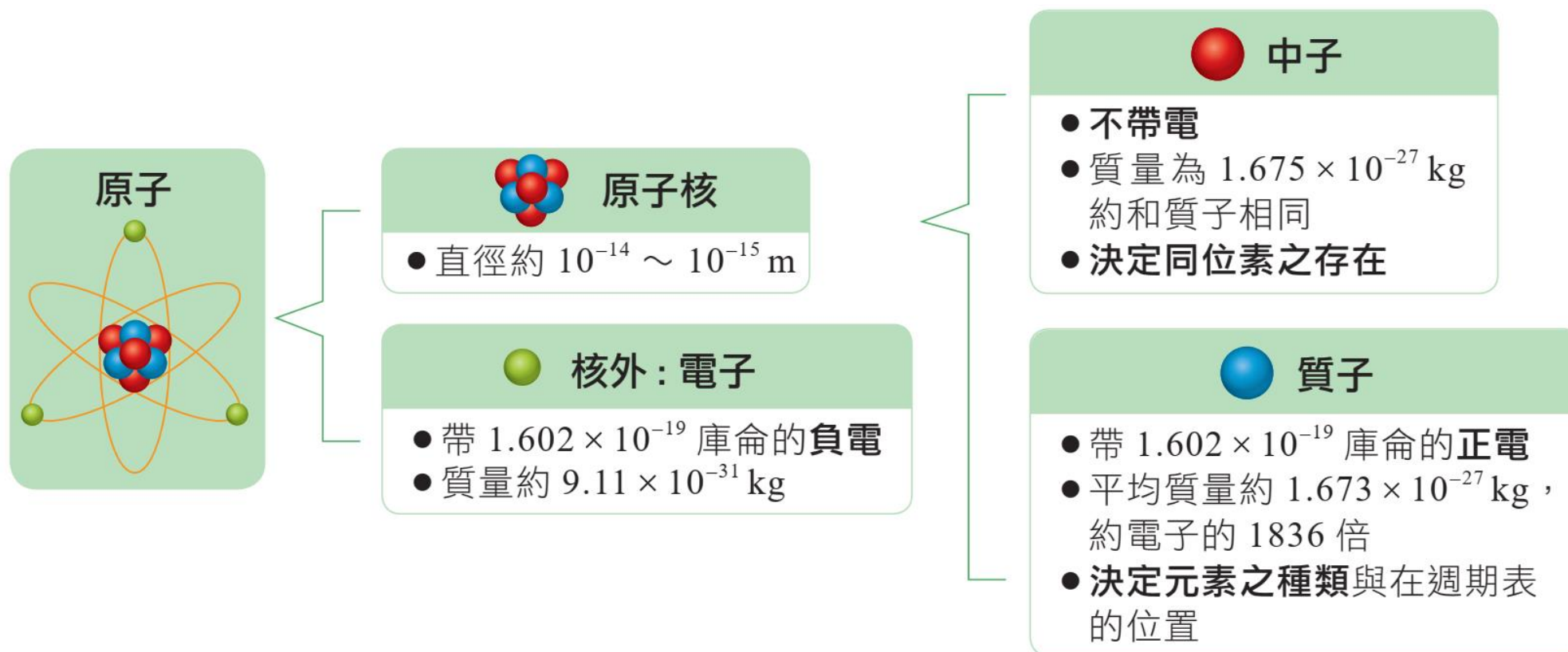
1.2 Types of Solids

1.3 Space Lattices

1.4 The Diamond Structure

1.5 Atomic Bonding

原子結構



氫原子模型

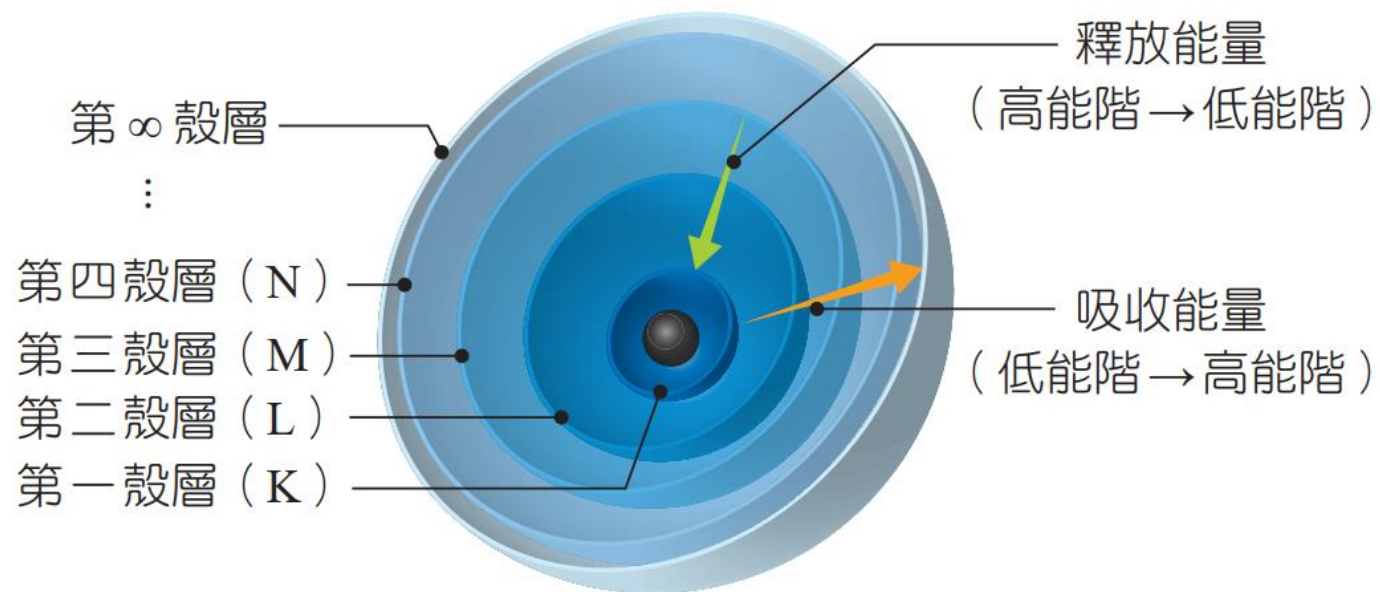


圖 1-32 原子中同心球切面，電子在不同能階間的躍遷示意圖

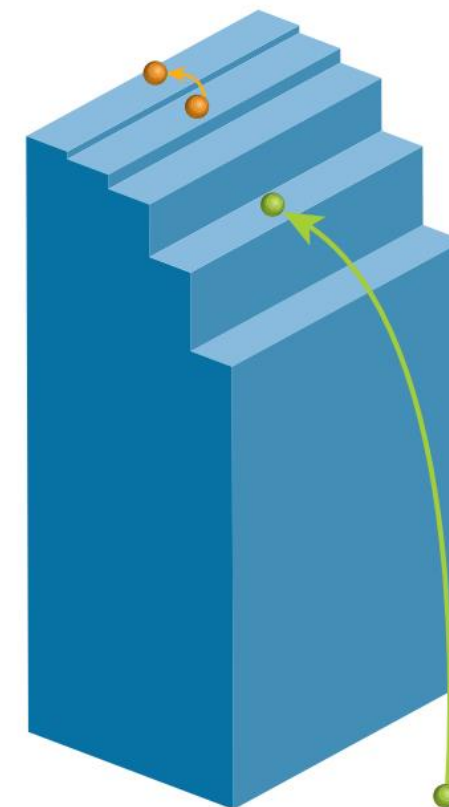
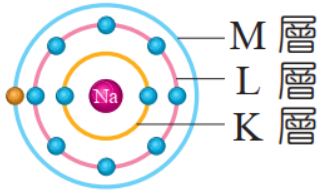










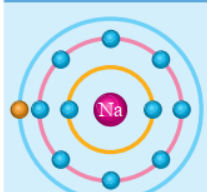
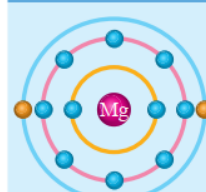
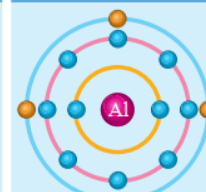
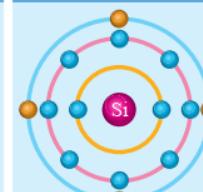
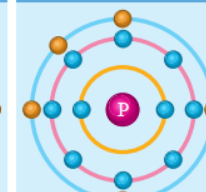
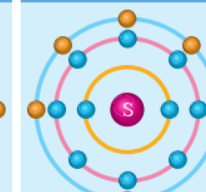
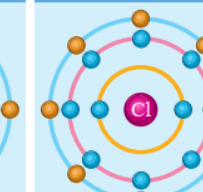
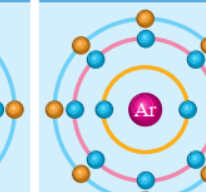


圖 1-31 電子能階示意圖

電子排列示意圖

氫 (${}_1\text{H}$)	 <div>● 內層電子 ● 最外層電子 (價電子)</div>						氦 (${}_2\text{He}$)
 1	 2						
鋰 (${}_3\text{Li}$)	鈹 (${}_4\text{Be}$)	硼 (${}_5\text{B}$)	碳 (${}_6\text{C}$)	氮 (${}_7\text{N}$)	氧 (${}_8\text{O}$)	氟 (${}_9\text{F}$)	氖 (${}_{10}\text{Ne}$)
 2, 1	 2, 2	 2, 3	 2, 4	 2, 5	 2, 6	 2, 7	 2, 8
鈉 (${}_{11}\text{Na}$)	鎂 (${}_{12}\text{Mg}$)	鋁 (${}_{13}\text{Al}$)	矽 (${}_{14}\text{Si}$)	磷 (${}_{15}\text{P}$)	硫 (${}_{16}\text{S}$)	氯 (${}_{17}\text{Cl}$)	氬 (${}_{18}\text{Ar}$)
 2, 8, 1	 2, 8, 2	 2, 8, 3	 2, 8, 4	 2, 8, 5	 2, 8, 6	 2, 8, 7	 2, 8, 8
1	2	3	4	5	6	7	8
價電子數							(He除外)

半導體材料

半導體，也就是導電性質介於金屬與絕緣體中間

- 元素半導體 elemental semiconductor，如 Si, Ge
- 化合物半導體 compound semiconductor，如 GaAs, InP

Table 1.1 | A portion of the periodic table

III	IV	V
5 B Boron	6 C Carbon	
13 Al Aluminum	14 Si Silicon	15 P Phosphorus
31 Ga Gallium	32 Ge Germanium	33 As Arsenic
49 In Indium		51 Sb Antimony

Table 1.2 | A list of some semiconductor materials

Elemental semiconductors	
Si	Silicon
Ge	Germanium
Compound semiconductors	
AlP	Aluminum phosphide
AlAs	Aluminum arsenide
GaP	Gallium phosphide
GaAs	Gallium arsenide
InP	Indium phosphide

週期表

IA																		VIIIA	
1 1.008 H Hydrogen												2 4.0026 He Helium							
IIA												IIIA	IVA	VA	VIA	VIIA			
3 6.939 Li Lithium	4 9.012 Be Beryllium	Transition Metals										5 10.811 B Boron	6 12.011 C Carbon	7 14.007 N Nitrogen	8 15.999 O Oxygen	9 18.998 F Florine	10 20.183 Ne Neon		
11 22.989 Na Sodium	12 24.312 Mg Magnesium	IIIB	IVB	VB	VIB	VIIB	VIIIB		IB		IIB	13 26.981 Al Aluminum	14 28.086 Si Silicon	15 30.974 P Phosphorus	16 32.064 S Sulfur	17 35.453 Cl Chlorine	18 39.948 Ar Argon		
19 39.102 K Potassium	20 40.08 Ca Calcium	21 44.956 Sc Scandium	22 47.90 Ti Titanium	23 50.942 V Vanadium	24 51.996 Cr Chromium	25 54.938 Mn Manganese	26 55.847 Fe Iron	27 58.933 Co Cobalt	28 58.71 Ni Nickel	29 63.54 Cu Copper	30 65.37 Zn Zinc	31 69.72 Ga Gallium	32 72.59 Ge Germanium	33 74.922 As Arsenic	34 78.96 Se Selenium	35 79.909 Br Bromine	36 83.80 Kr Krypton		
37 85.47 Rb Rubidium	38 87.62 Sr Strontium	39 88.905 Y Yttrium	40 91.22 Zr Zirconium	41 92.906 Nb Niobium	42 95.94 Mo Molybde- num	43 99 Tc Technitium	44 101.07 Ru Ruthenium	45 102.91 Rh Rhodium	46 106.4 Pd Palladium	47 107.87 Ag Silver	48 112.40 Cd Cadmium	49 114.82 In Indium	50 118.69 Sn Tin	51 121.75 Sb Antimony	52 127.60 Te Tellurium	53 126.904 I Iodine	54 131.30 Xe Xenon		
55 132.90 Cs Cesium	56 137.34 Ba Barium	57 138.91 La Lanthanum	72 178.49 Hf Hafnium	73 180.95 Ta Tantalum	74 183.85 W Tungsten	75 186.2 Re Rhenium	76 190.2 Os Osmium	77 192.2 Ir Iridium	78 195.09 Pt Platinum	79 196.967 Au Gold	80 200.59 Hg Mercury	81 204.37 Tl Thallium	82 207.19 Pb Lead	83 208.98 Bi Bismuth	84 210 Po Polonium	85 210 At Astatine	86 222 Rn Radon		
87 223 Fr Francium	88 226 Ra Radium	89 227 Ac Actinium	104 Rf	105 Ha	106 Sg	107 Uns	108 Uno	109 Une	110 Uun										
										Nonmetals									
										↑ Metalloids									



Nonmetals

Metalloids
(semimetals)

Lanthanides

Actinides

58 140.12 Ce Cerium	59 140.91 Pr Praseodymium	60 144.24 Nd Neodymium	61 147 Pm Promethium	62 150.35 Sm Samarium	63 151.96 Eu Europium	64 157.25 Gd Gadolinium	65 158.92 Tb Terbium	66 162.50 Dy Dysprosium	67 164.93 Ho Holmium	68 167.26 Er Erbium	69 168.93 Tm Thulium	70 173.04 Yb Ytterbium	71 174.97 Lu Lutetium
90 232.04 Th Thorium	91 231 Pa Protactinium	92 238.03 U Uranium	93 237 Np Neptunium	94 242 Pu Plutonium	95 243 Am Americium	96 247 Cm Curium	97 247 Bk Berkelium	98 249 Cf Californium	99 254 Es Einsteinium	100 253 Fm Fermium	101 256 Md Mendelevium	102 253 No Nobelium	103 257 Lr Lawrencium

固態物質種類

非晶 Amorphous

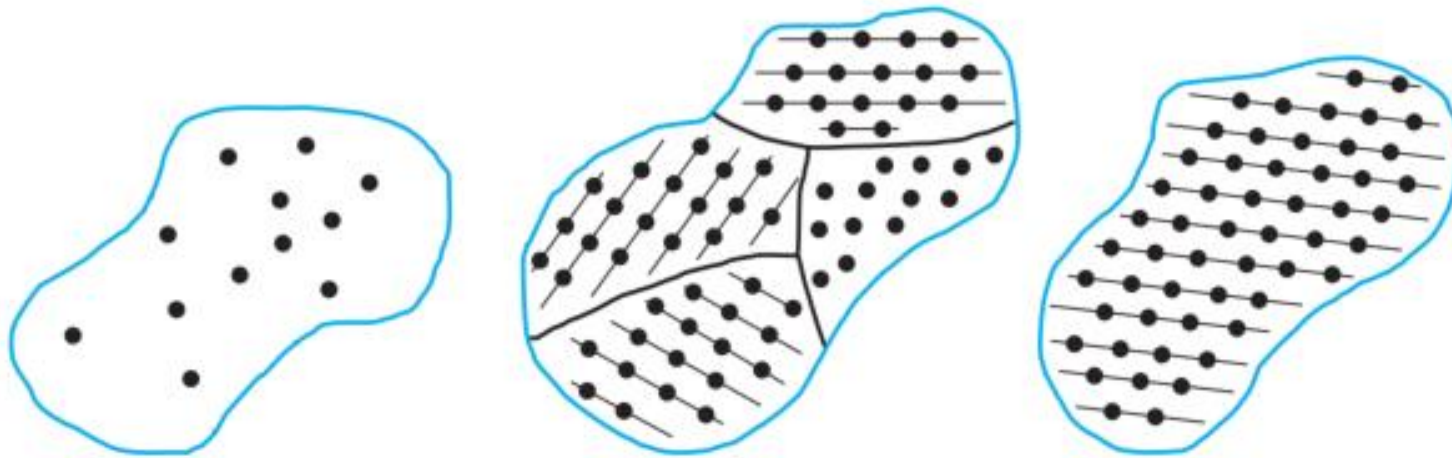
有序程度非常低 (degree of order)，原子排列雜亂無章 ($< 10\text{ nm}$)

多晶 Poly-crystalline

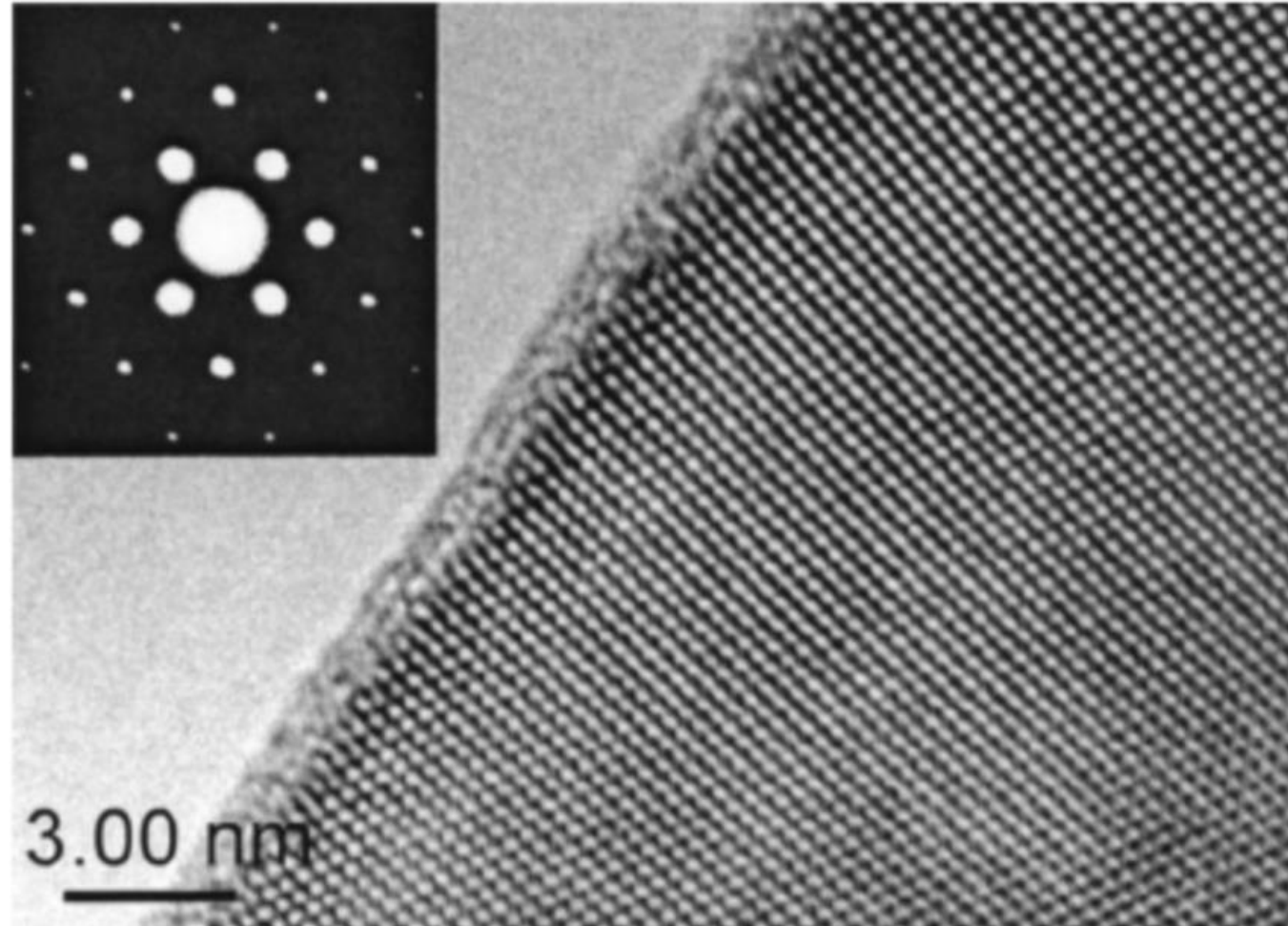
有序程度中等 ($100\text{ nm} - 10\text{ }\mu\text{m}$)，每個有序排列的區域稱為晶粒 (grains)，每個晶粒之間的大小與排列方向不盡相同。

單晶 Single-crystalline

材料內原子的排序程度非常高，方向一致，幾乎呈現完美狀態



單晶矽



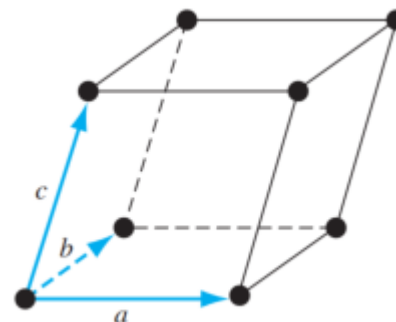
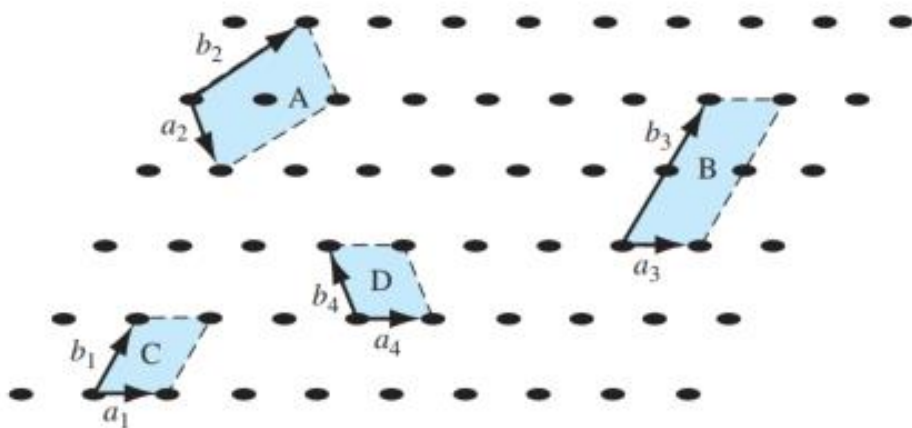
Space Lattices

晶格 (Lattice)：一個區域或空間中，具有規則幾何排列的點或物體

單位晶胞 (Unit cell)：具對稱性的原子排列，可在空間上重複構建整個晶格

晶格常數 (Lattice constant)：單位晶胞的物理尺寸，通常以向量描述

原胞 (Primitive cell)：無法再被切割的單位晶格

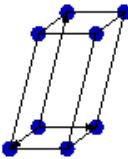
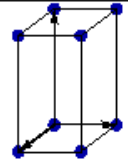
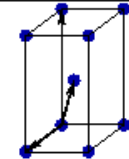
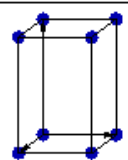
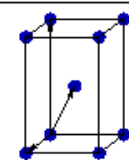
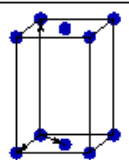
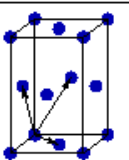
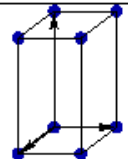
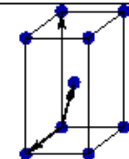
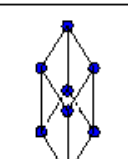
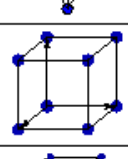
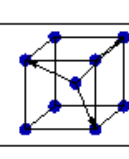
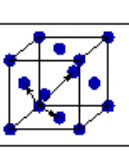
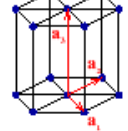


$$\vec{r} = p\vec{a} + q\vec{b} + s\vec{c}$$

Primitive vector

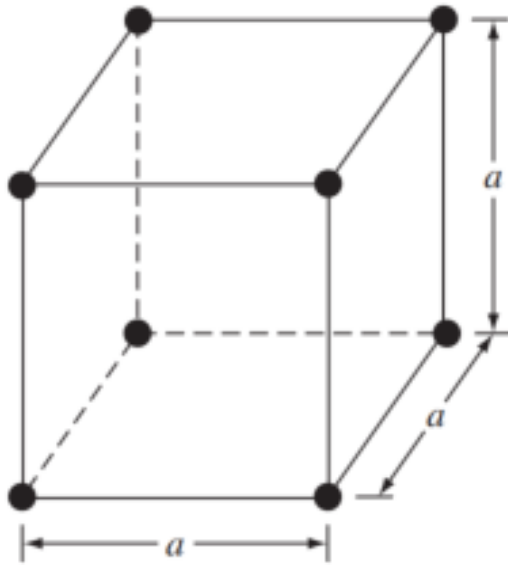
p, q, s : integer

Crystal System

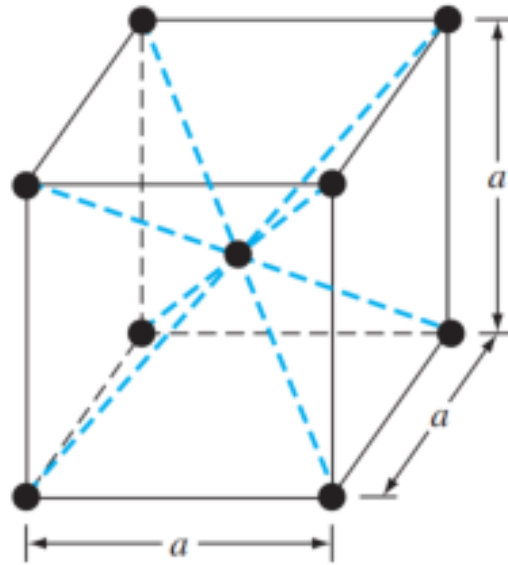
Bravais lattice	Parameters	Simple (P)	Volume centered (I)	Base centered (C)	Face centered (F)
三斜晶系 Triclinic	$a_1 \neq a_2 \neq a_3$ $\alpha_{12} \neq \alpha_{23} \neq \alpha_{31}$				
單斜晶系 Monoclinic	$a_1 \neq a_2 \neq a_3$ $\alpha_{23} = \alpha_{31} = 90^\circ$ $\alpha_{12} \neq 90^\circ$				
正交晶系 Orthorhombic	$a_1 \neq a_2 \neq a_3$ $\alpha_{12} = \alpha_{23} = \alpha_{31} = 90^\circ$				
四方晶系 Tetragonal	$a_1 = a_2 \neq a_3$ $\alpha_{12} = \alpha_{23} = \alpha_{31} = 90^\circ$				
菱方晶系 Trigonal	$a_1 = a_2 = a_3$ $\alpha_{12} = \alpha_{23} = \alpha_{31} < 120^\circ$				
立方晶系 Cubic	$a_1 = a_2 = a_3$ $\alpha_{12} = \alpha_{23} = \alpha_{31} = 90^\circ$				
六方晶系 Hexagonal	$a_1 = a_2 \neq a_3$ $\alpha_{12} = 120^\circ$ $\alpha_{23} = \alpha_{31} = 90^\circ$				

Cubic crystal system

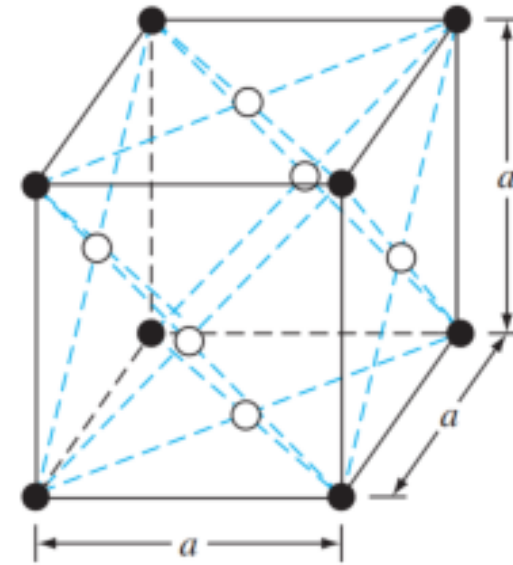
Simple cubic
(SC)
簡單立方



Body-centered cubic
(BCC)
體心立方



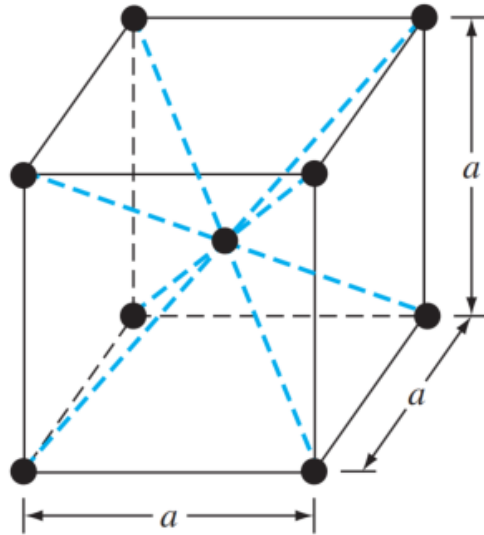
Face-centered cubic
(FCC)
面心立方



Example 1.1 Find the Volume Density

Objective: Find the volume density of atoms in a crystal.

Consider a single-crystal material that is a body-centered cubic, as shown in Figure 1.5b, with a lattice constant $a = 5 \text{ \AA} = 5 \times 10^{-8} \text{ cm}$. A corner atom is shared by eight unit cells that meet at each corner so that each corner atom effectively contributes one-eighth of its volume to each unit cell. The eight corner atoms then contribute an equivalent of one atom to the unit cell. If we add the body-centered atom to the corner atoms, each unit cell contains an equivalent of two atoms.

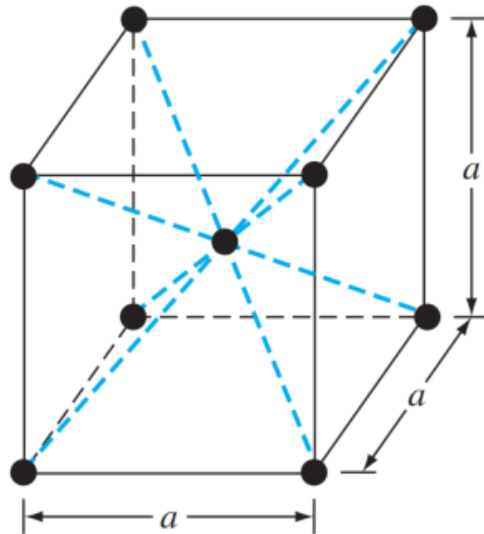


$$\text{Volume Density} = \frac{\# \text{ atoms per unit cell}}{\text{volume of unit cell}}$$

Example 1.1 Find the Volume Density

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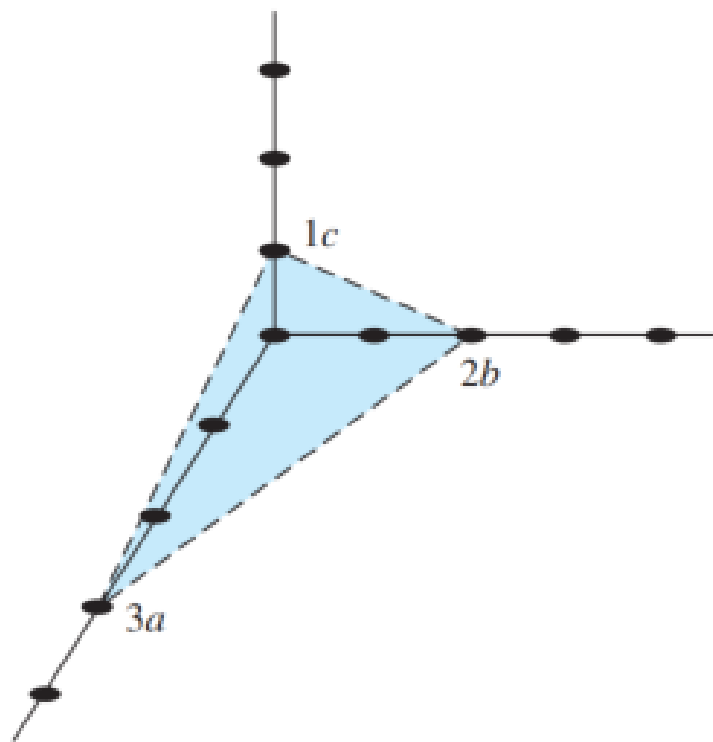
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$$\frac{\left(8 \times \frac{1}{8} + 1\right)}{\left(5 \times 10^{-8}\right)^3} = 1.6 \times 10^{22} \quad \text{Atoms/cm}^3$$

Crystal Planes and Miller Indices

如何描述一個晶面 → Miller indices



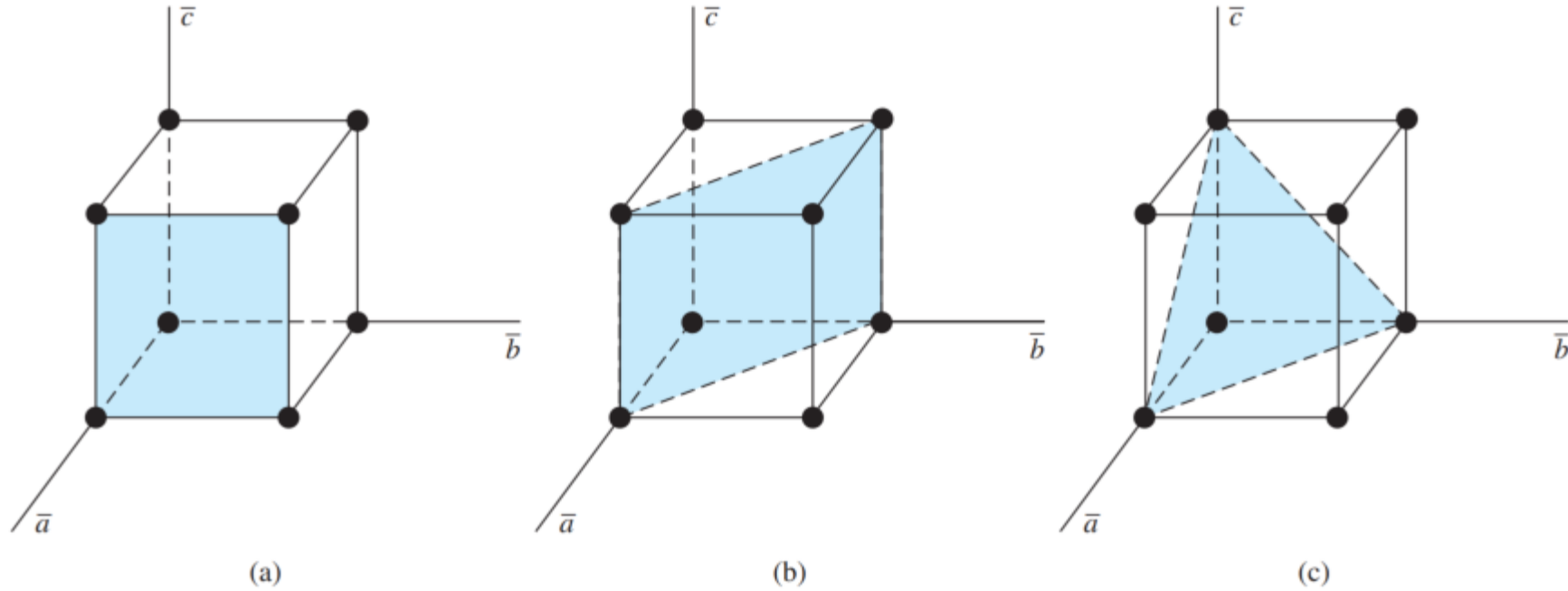
$$\vec{g} = p\vec{a} + q\vec{b} + s\vec{c} = 3\vec{a} + 2\vec{b} + 1\vec{c}$$

$$\left(\frac{1}{p}, \frac{1}{q}, \frac{1}{s}\right) = \left(\frac{1}{3}, \frac{1}{2}, \frac{1}{1}\right) = (2, 3, 6) = (236)$$

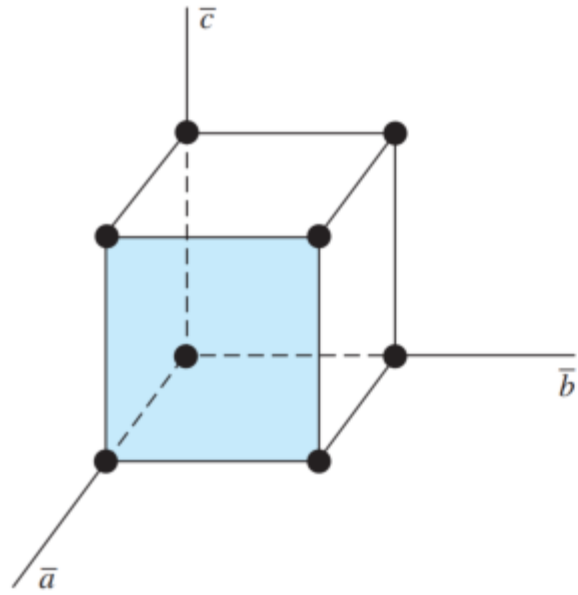


乘上三個分母的最小公倍數 6

Crystal Planes and Miller Indices

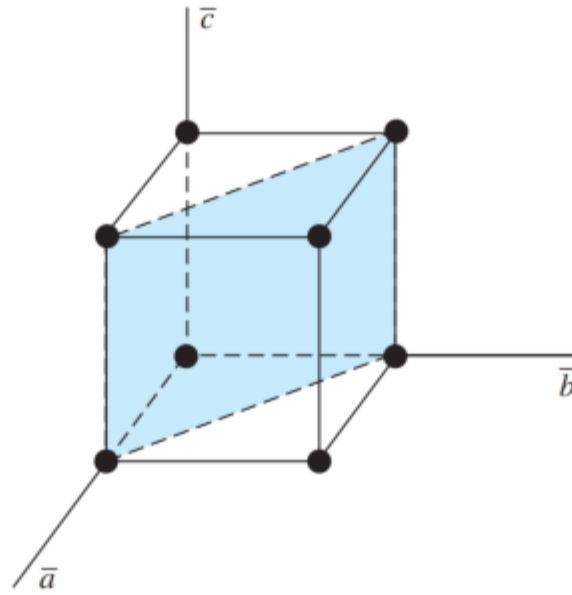


Crystal Planes and Miller Indices



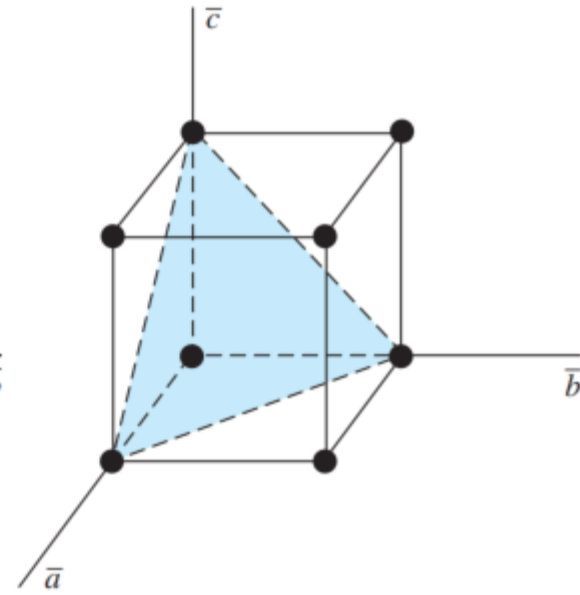
(a)

(100)



(b)

(110)



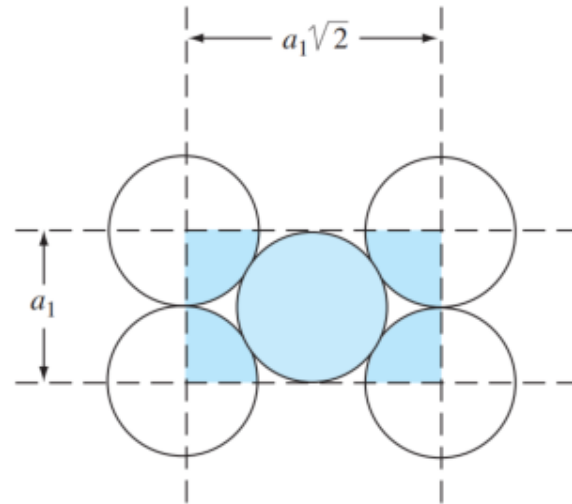
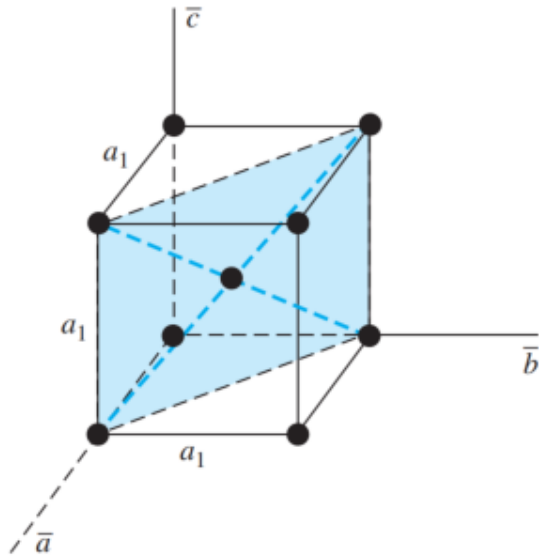
(c)

(111)

Example 1.3 Calculate the Surface Density

Objective: Calculate the surface density of atoms on a particular plane in a crystal.

Consider the body-centered cubic structure and the (110) plane shown in Figure 1.9a. Assume the atoms can be represented as hard spheres with the closest atoms touching each other. Assume the lattice constant is $a_1 = 5 \text{ \AA}$. Figure 1.9b shows how the atoms are cut by the (110) plane.

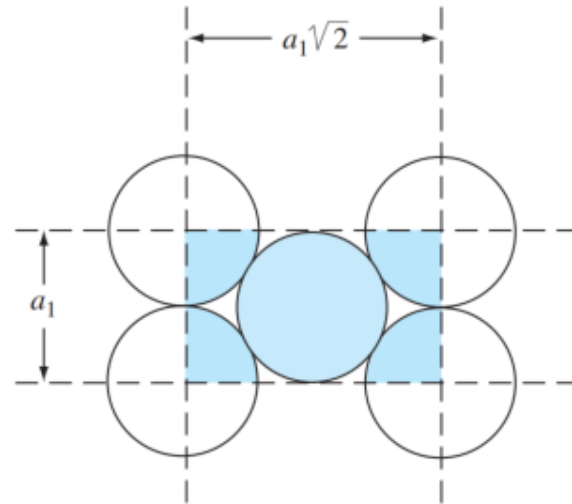
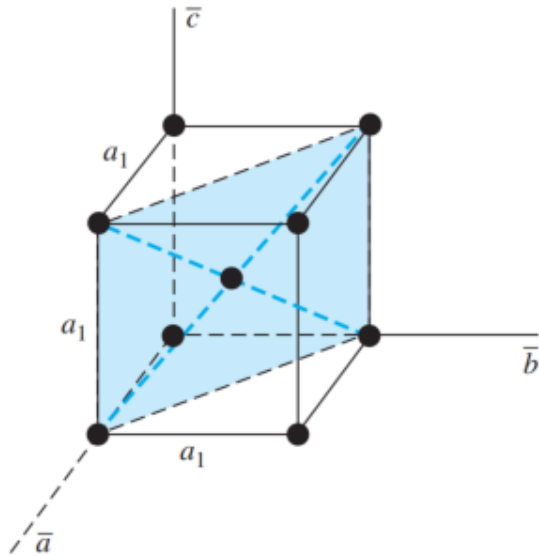


$$\text{Surface Density} = \frac{\text{\# of atoms per lattice plane}}{\text{area of lattice plane}}$$

Example 1.3 Calculate the Surface Density

Objective: Calculate the surface density of atoms on a particular plane in a crystal.

Consider the body-centered cubic structure and the (110) plane shown in Figure 1.9a. Assume the atoms can be represented as hard spheres with the closest atoms touching each other. Assume the lattice constant is $a_1 = 5 \text{ \AA}$. Figure 1.9b shows how the atoms are cut by the (110) plane.

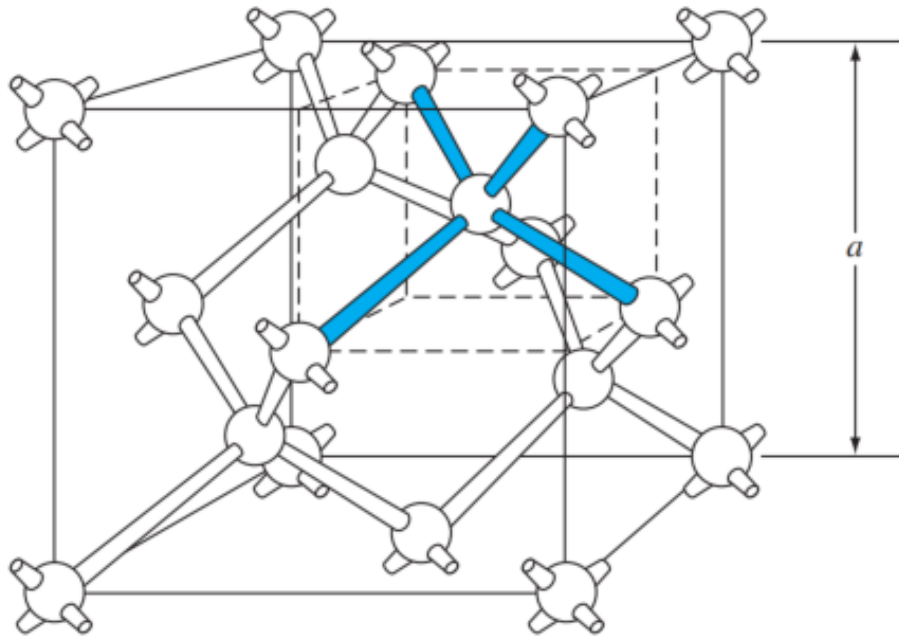


$$\frac{\left(4 \times \frac{1}{4} + 1\right)}{(5 \times 10^{-8})(5 \times 10^{-8} \times \sqrt{2})} = 5.66 \times 10^{14}$$

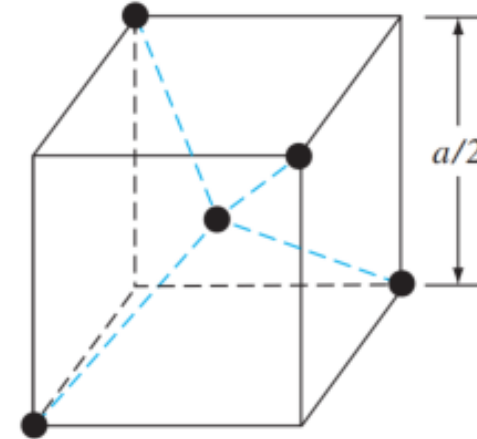
Atoms/cm²

鑽石結構 The Diamond Structure

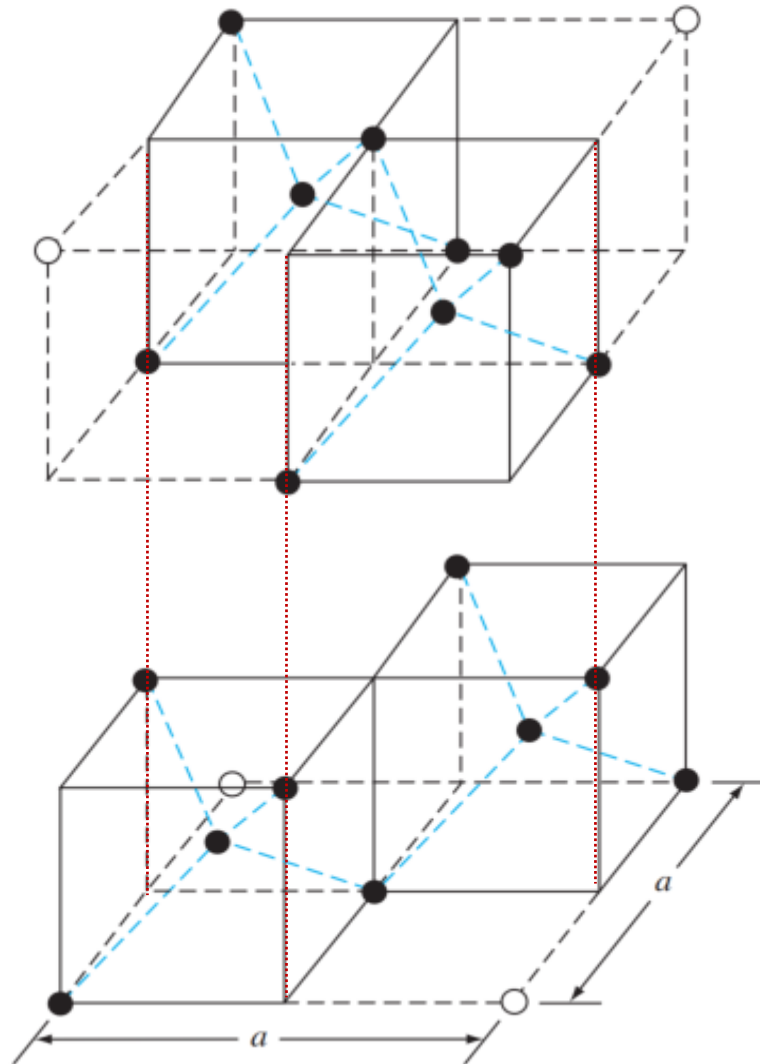
- 四面體 (tetrahedral structure) 是一個體心立方去掉四個角落的原子組成。
- 鑽石結構基本上是由多個四面體 (tetrahedral structure) 組成的。



Tetrahedral structure

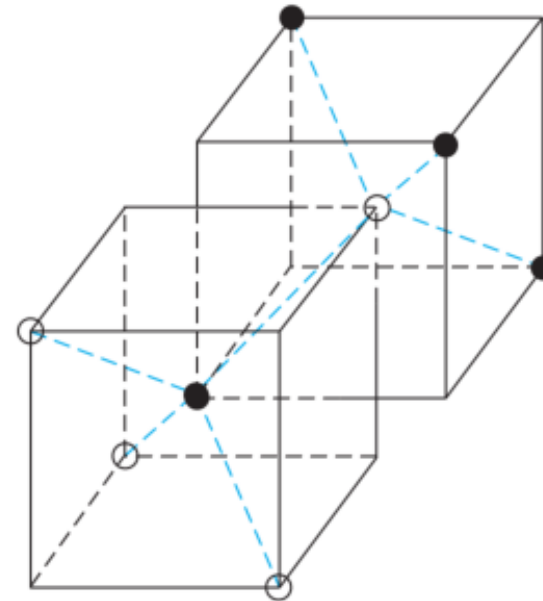
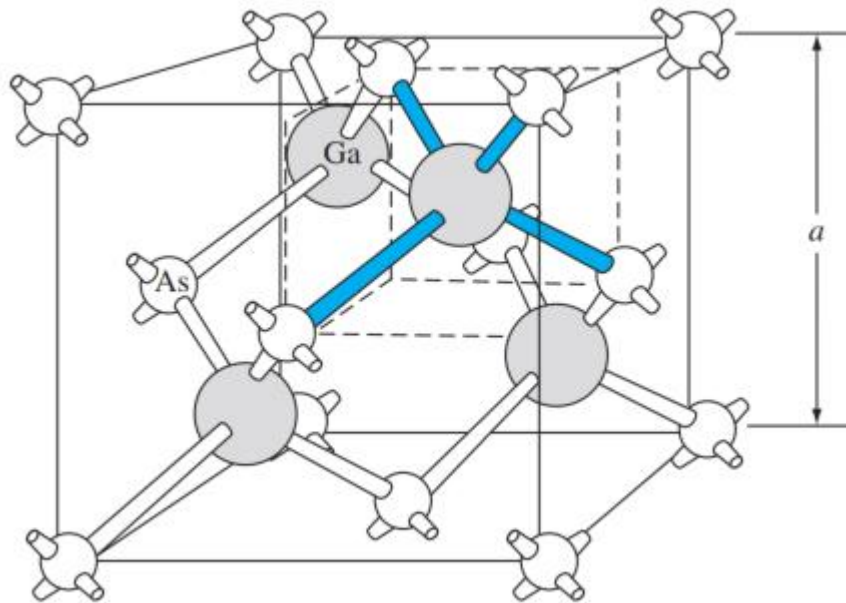


The Diamond Structure



閃鋅結構 Zincblende structure

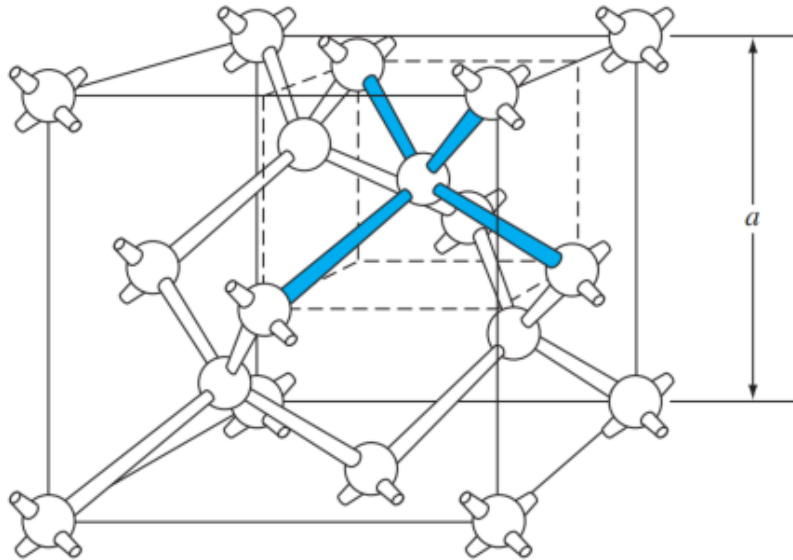
- 閃鋅礦結構與金剛石結構的不同之處僅在於晶格中有兩種不同類型的原子
- 每個 Ga 原子有四個最近的 As 原子，每個 As 有四個最近的 Ga 原子。



Test Your Understanding

TYU 1.4 Consider the diamond unit cell shown in Figure 1.11. Determine the (a) number of corner atoms, (b) number of face-centered atoms, and (c) number of atoms totally enclosed in the unit cell. [Ans. (a) 8; (b) 6; (c) 8]

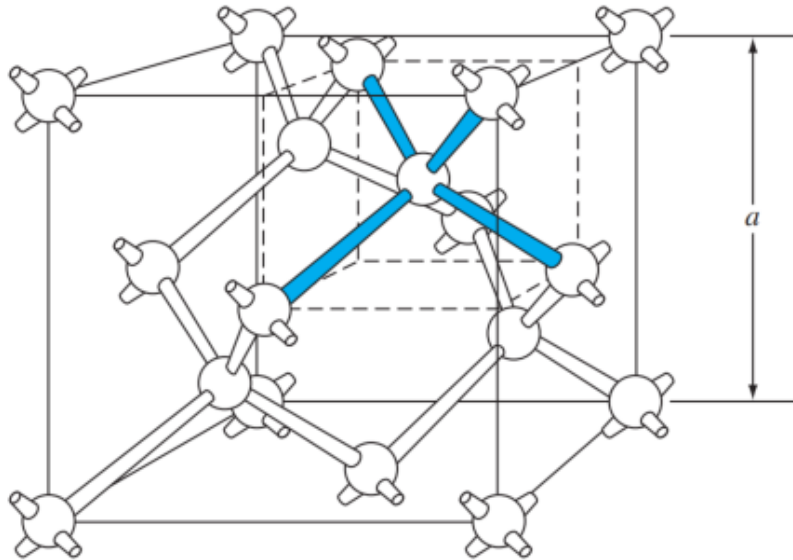
TYU 1.5 The lattice constant of silicon is 5.43 \AA . Calculate the volume density of silicon atoms. [Ans. $5 \times 10^{22} \text{ cm}^{-3}$]



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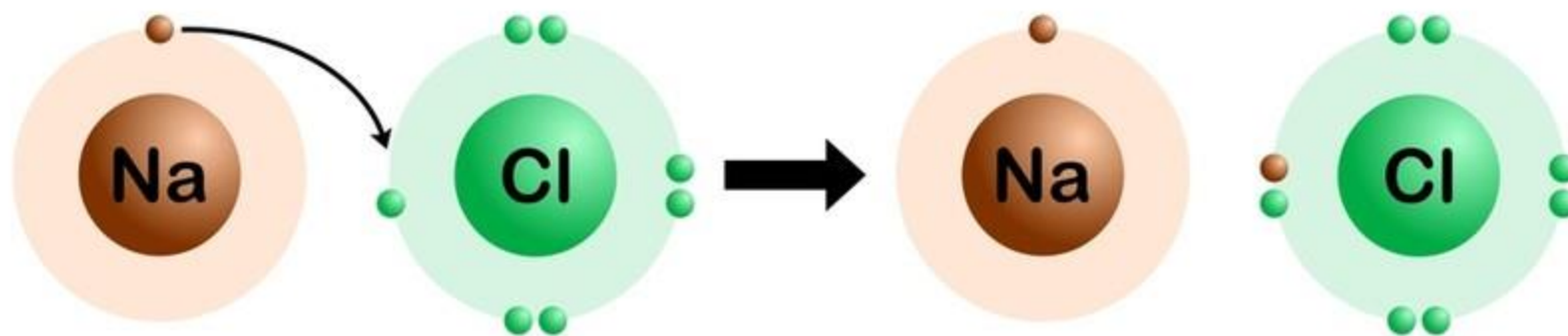
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$$\frac{\left(8 \times \frac{1}{8} + 6 \times \frac{1}{2} + 4 \right)}{\left(5.43 \times 10^{-8} \right)^3} = 5 \times 10^{22} \text{ Atoms/cm}^3$$

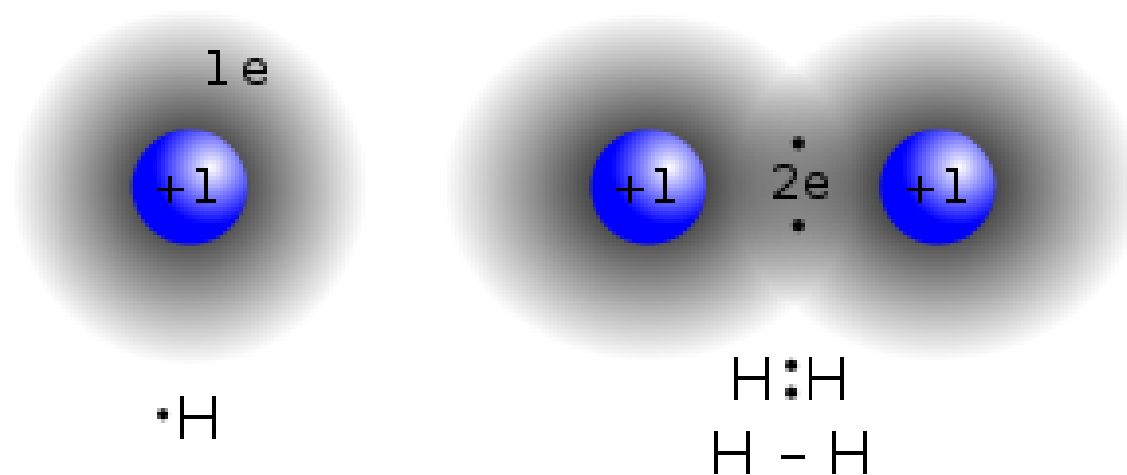
離子鍵 Ionic Bond

- 離子鍵通過兩個或多個原子失去或獲得電子而成為離子後形成。帶相反電荷的離子之間存在靜電吸引力，是離子化合物中主要交互作用。
- 此類經常是金屬與非金屬間形成，金屬元素失去電子，而非金屬元素得到電子。



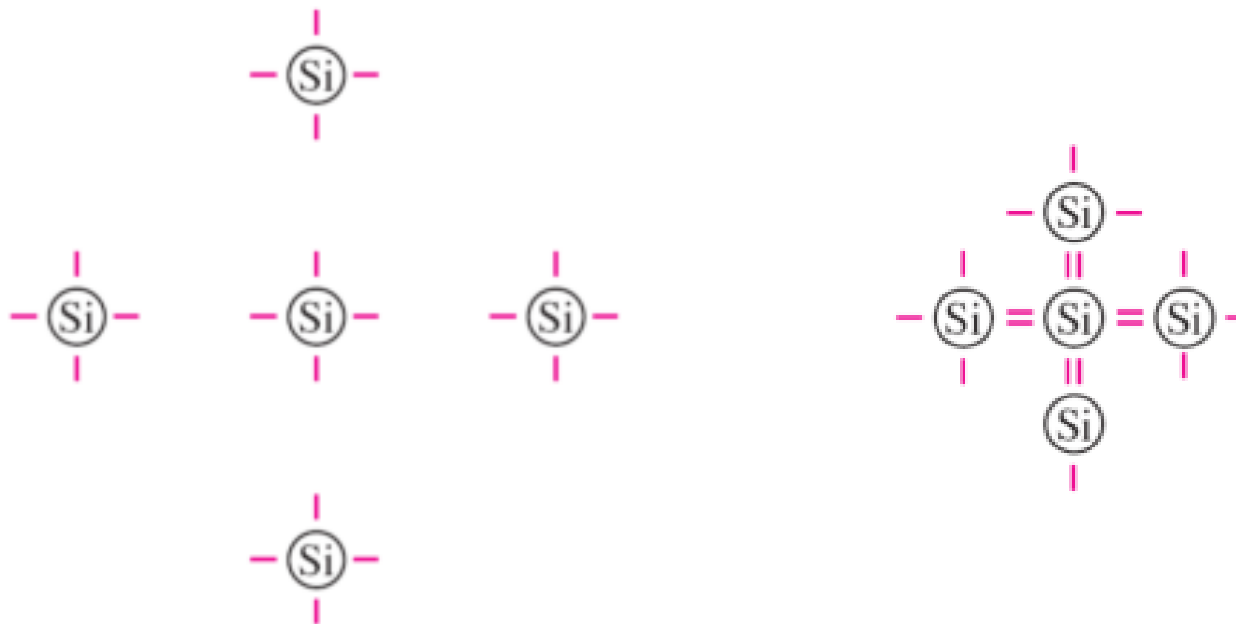
共價鍵 Covalent Bond

- 兩顆或以上非金屬原子共同使用它們的外層電子，在理想情況下達到電子飽和的狀態，由此組成比較穩定和堅固的化學結構。
- 與離子鍵不同，它們並沒有獲得或損失電子。同一種元素的原子或不同元素的原子都可以通過共價鍵結合，一般共價鍵結合的產物是分子，在少數情況下也可以形成晶體。



共價鍵 Covalent Bond

鄰近矽原子之間共享價電子，剛好滿足八隅體法則



金屬鍵 Metallic bond

- 游離電子與金屬離子之間的靜電吸引力組合而成。
- 由於電子是自由運動，金屬鍵沒有固定的方向，因而是非極性鍵。

